NSN 5962-01-462-6542

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View Online at https://aerobasegroup.com/nsn/5962-01-462-6542

Body Length:

1.280 inches

Body Outside Diameter:

Between 0.140 inches and 0.185 inches

Body Width:

Between 0.220 inches and 0.310 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Safcs cage 26512

Features Provided:

Hermetically sealed and burn in and monolithic and positive outputs

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

14 input

Case Outline Source And Designator:

-9 mil-m-38510

Current Rating Per Characteristic:

120.00 milliamperes forward current, nonrepetitive, peak total value minor

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit prom

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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